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Kind regards,

Team Nexperia

## INTEGRATED CIRCUITS

# DATA SHEET

## 74LVT1403

3.3V combined 8-bit bus receiver and 4-bit bus driver

Product specification

1998 Nov 12

IC23 Data Handbook





## 3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

#### **FEATURES**

- 4-bit 74LVT125-like bus driver
- 8-bit 74LVT14-like Schmitt trigger
- Bus drive +64mA/-32mA
- 7 bus inputs with common inversion control pin
- 32-pin TSSOP footprint
- DE pin with resistive pull up and active LOW for easier live insertion
- DE pin includes Schmitt trigger with typical 0.6V hysteresis

#### **DESCRIPTION**

The 74LVT1403 is a high-performance BiCMOS product designed for  $V_{\rm CC}$  operation at 3.3V.

This device combines the functionality of a 4-bit data path bus driver and 8-bit Schmitt trigger bus receiver, along with control logic in one 32-pin package.

The receiver inputs are Schmitt trigger type capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. The receiver outputs are 74LVT14 style with +32mA/-20mA drive capability. The receiver inputs include the bus hold feature.

The driver outputs feature power-up in 3-State/live insertion capability and are all controlled by the A/B, EN1, and EN2 control pins. The driver inputs include the bus hold feature.

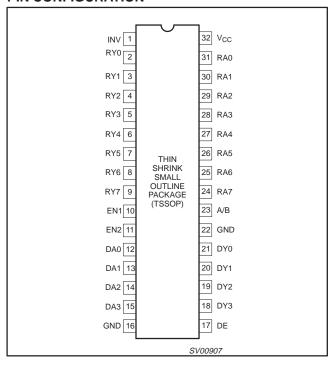
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub>	Propagation delay An to Yn	$C_L = 50pF; V_{CC} = 3.3V$	4.5	ns
t <sub>PHL</sub>	Propagation delay An to Yn	$C_L = 50pF; V_{CC} = 3.3V$	4.0	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0V \text{ or } 3.0V$	3	pF
Icc	Total supply current	Outputs low, $V_{CC} = 3.6V$	4	mA

### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
32-pin plastic TSSOP	-40°C to +85°C	74LVT1403 DR	74LVT1403 DR	SOT487-1

## **PIN CONFIGURATION**



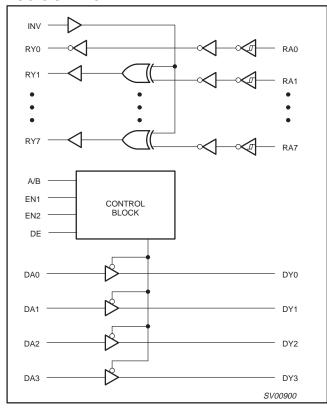
## **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
31, 30, 29, 28, 27, 26, 25, 24	RA0-RA7	Receive Data inputs
2, 3, 4, 5, 6, 7, 8, 9	RY0-RY7	Receive Data outputs
12, 13, 14, 15	DA0-DA3	Driver Data inputs
21, 20, 19, 18	DY0-DY3	Driver Data outputs
10, 11	EN1, EN2	Driver Output enables
23	A/B	Mode control for enables
1	INV	Inversion control
16, 22	GND	Ground (0V)
32	V <sub>CC</sub>	Positive supply voltage
17	DE	Driver output enable active LOW with resistive pull up

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

## **LOGIC SYMBOL**



### **FUNCTION TABLE – RECEIVER**

INP	JTS	OUTPUTS		
RA0-RA7	RA0-RA7 INV		RY1-RY7	
L	Х	Н	_	
Н	Х	L	_	
L	L	_	L	
Н	L	_	Н	
L	Н	_	Н	
Н	Н	_	L	

H = High voltage level L = Low voltage level

X = Don't care

— = Reported on different line

## **FUNCTION TABLE - DRIVER**

	CONT	ROL INPU	гѕ	OUTPUT CONDITION
DE	A/B	EN1	EN2	DY Status
L	L	L	L	А
L	L	Х	Н	Z
L	L	Н	Х	Z
L	Н	Н	Н	А
L	Н	Х	L	Z
L	Н	L	Х	Z
Н	Х	Х	Х	Z

High voltage level Low voltage level

X = Don't care Z = High impedance "off" state

A = Active

## **DATA PATH IN ACTIVE MODE**

INPUT	OUTPUT
DAn	DYn
L	L
Н	Н

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

## ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
$V_{I}$	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V
	DVs DC sutput surrent	Output in Low state	128	mA
	DYn DC output current	Output in High state	-64	mA
lout	RYn DC output current	Output in Low state	-32	mA
		Output in High state	64	mA
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		LIM	LIMITS		
STWIBUL	PARAMETER		MIN	MAX	UNIT	
V <sub>CC</sub>	DC supply voltage			3.6	V	
VI	Input voltage	0	5.5	V		
V <sub>IH</sub>	High-level input voltage	2.0		V		
V <sub>IL</sub>	Low-level Input voltage		0.8	V		
	High level cuts it comest			-32	mA	
Іон	High-level output current	RYn		-20	mA	
	Low lovel output oursest	DYn		32	mA	
I <sub>OL</sub>	Low-level output current			32	mA	
	Low-level output current; current duty cycle ≤ 50%, f ≥ 1kHz DYn			64	mA	
Δt/ΔV	Input transition rise or fall rate; Outputs enabled			10	ns/V	
T <sub>amb</sub>	Operating free-air temperature range	·	-40	+85	°C	

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

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### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

						LIMITS		UNIT		
SYMBOL	PARAMETER		TEST CONDITIONS		Temp :	= -40°C to +85°C				
					MIN	TYP <sup>1</sup>	MAX			
$V_{T+}$	Positive-going threshold	RAn	V <sub>CC</sub> = 3.3V		1.5	1.7	2.0	V		
$V_{T-}$	Negative-going threshold	RAn	V <sub>CC</sub> = 3.3V	0.9	1.1	1.3	٧			
$\Delta V_{T}$	Hysteresis	RAn	$V_{CC} = 3.3V$		0.4	0.6		V		
V <sub>IK</sub>	Input clamp voltage		$V_{CC} = 2.7V; I_{IK} = -18mA$				-1.2	V		
			$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -10$	00μΑ	V <sub>CC</sub> -0.2			V		
		RYn	$V_{CC} = 2.7V; I_{OH} = -6mA$		2.4			V		
$V_{OH}$	High-level output		$V_{CC} = 3.0V; I_{OH} = -20mA$		2.0			V		
VOH	voltage		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -10$	00μΑ	V <sub>CC</sub> -0.2	V <sub>CC</sub> -0.1		V		
		DYn	$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V		
			$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.2		V		
			$V_{CC} = 2.7V; I_{OL} = 100\mu A$				0.2	V		
		RYn	$V_{CC} = 2.7V; I_{OL} = 24mA$				0.5	V		
			$V_{CC} = 3.0V; I_{OL} = 32mA$				0.5	V		
$V_{OL}$	Low-level output voltage	DYn	$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.1	0.2	V		
VOL   Low lovel output	2011 lovor output voltago		$V_{CC} = 2.7V; I_{OL} = 24mA$			0.3	0.5	V		
			$V_{CC} = 3.0V; I_{OL} = 16mA$			0.25	0.4	V		
		$V_{CC} = 3.0V; I_{OL} = 32mA$				0.3	0.5	V		
			$V_{CC} = 3.0V; I_{OL} = 64mA$			0.4	0.55	V		
			$V_{CC} = 0 \text{ or } 3.6V; V_I = 5.5V$	All inputs		1	10	4		
			$V_{CC} = 3.6V; V_I = V_{CC}$	Control pins		±0.1	±1	]		
l <sub>l</sub>	Input leakage current		$V_{CC} = 3.6V; V_{I} = GND$	INV, EN1, EN2, A/B		±0.1	±1	μΑ		
-1				DE		-60	-100	J 1		
			$V_{CC} = 3.6V; V_I = V_{CC}$	Data port <sup>4</sup>		0.1	1			
			$V_{CC} = 3.6V; V_I = GND$	'		-1	<b>–</b> 5	μΑ		
I <sub>OFF</sub>	Output off current		$V_{CC} = 0V$ ; $V_{I}$ or $V_{O} = 0$ to 4.5	5V		1	±100	μΑ		
I <sub>HOLD</sub>	Bus hold current RA and I	DΑ	$V_{CC} = 3V; V_I = 0.8V$		75	150		μΑ		
TIOLD	inputs		$V_{CC} = 3V; V_I = 2.0V$		<del>-</del> 75	-150		μΑ		
$I_{EX}$	Current into an output in the High state when V <sub>O</sub> > V <sub>CO</sub>		$V_O = 5.5V; V_{CC} = 3.0V$			60	125	μΑ		
I <sub>PU/PD</sub>	Power-up/down 3-State or current <sup>3</sup>	utput	$V_I = GND \text{ or } V_{CC};$	$V_{CC} \le 1.2V$ ; $V_O = 0.5V$ to $V_{CC}$ ; $V_I = GND$ or $V_{CC}$ ; $EN1$ , $EN2$ , $A/B$ , $DE = Don't$ care		±1	±100	μА		
I <sub>OZH</sub>	3-State output high curren	t	$V_{CC} = 3.6V; V_{O} = 3.0V$	$V_{CC} = 3.6V; V_O = 3.0V$		1	5	μΑ		
I <sub>OZL</sub>	3-State output low current		$V_{CC} = 3.6V; V_O = 0.5V$					-1	<b>-</b> 5	μΑ
I <sub>CCH</sub>	Quiescent supply current		$V_{CC} = 3.6V$ ; Outputs High, $V_I = GND$ or $V_I = GND$	/ <sub>CC.</sub> I <sub>O</sub> = 0		0.13	0.19	mA		
I <sub>CCL</sub>			$V_{CC} = 3.6V$ ; Outputs Low, $V_I = GND$ or $V_I = GND$	' <sub>CC,</sub> I <sub>O</sub> = 0		4	11	mA		
I <sub>CCZ</sub>			$V_{CC} = 3.6V$ ; Outputs Disabled, $V_I = GND$	,		0.13	0.19	mA		
Δl <sub>CC</sub>	Additional supply current prince input pin <sup>2</sup>	oer	V <sub>CC</sub> = 3V to 3.6V; One input Other inputs at V <sub>CC</sub> or GND	t at V <sub>CC</sub> –0.6V,		0.1	0.2	mA		

## NOTES:

- All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
   This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.
   This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V, a transition time of 100 $\mu$ sec is permitted. This parameter is valid for  $T_{amb}$  = 25 $^{\circ}$ C only.
- 4. Unused pins at V<sub>CC</sub> or GND.
- 5. All RYn outputs High. All DYn outputs pulled up to V<sub>CC</sub> or pulled down to ground.

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

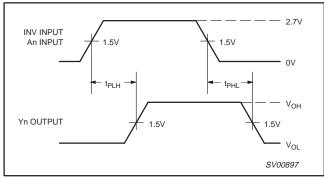
### **AC CHARACTERISTICS**

RAn = Receive inputs; Ryn = Receive outputs DAn = Driver inputs; Dyn = Driver outputs

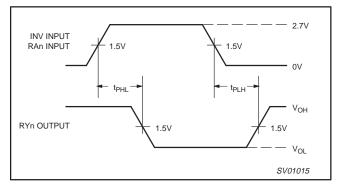
SYMBOL	PARAMETER	WAVEFORM	V <sub>C</sub>	$V_{CC}$ = 3.3V $\pm$ 0.3V			UNIT	
			MIN	MIN TYP		MAX	$\neg$	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay RA0 to RY0	2	1.0 1.0	3.8 3.2	5.7 4.4	6.9 4.3	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay RAn to RYn (n = 1 to 7)	1, 2	2.0 2.0	4.5 4.0	6.7 5.7	7.8 6.4	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay Invert to RYn	1, 2	2.0 2.0	4.0 3.6	6.3 5.5	7.1 7.4	ns	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay DAn to DYn	1	1.0 1.0	3.1 2.0	4.2 3.0	4.7 3.5	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time ENn to DYn with A/B = 0	3	2.0 2.0	4.8 4.3	7.1 6.7	9.6 7.4	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time ENn to DYn with A/B = 1	4	2.0 2.0	4.3 4.0	6.5 6.1	7.8 6.6	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time ENn to DYn with A/B =0	3	2.0 2.0	4.7 4.0	7.1 6.3	8.2 6.9	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time ENn to DYn with A/B =1	4	2.0 2.0	4.2 4.0	6.8 6.2	8.3 6.5	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time A/B to DYn	3, 4	2.0 2.0	5.0 4.2	8.6 6.5	9.5 7.2	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time A/B to DYn	3, 4	2.0 2.0	5.1 4.3	7.5 6.2	7.7 6.6	ns	
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time DE to DYn	3	2.0 2.0	5.1 4.7	7.6 6.8	9.1 7.5	ns	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time DE to DYn	3	2.0 2.0	5.9 4.9	9.3 7.2	9.7 7.7	ns	

## **AC WAVEFORMS**

 $V_{M} = 1.5V$ ,  $V_{IN} = GND$  to 2.7V



Waveform 1. Input (An) to Output (Yn) Propagation Delays



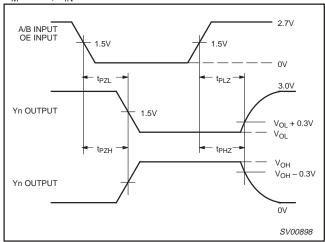
Waveform 2. Input (An) to Output (Yn) Propagation Delays

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

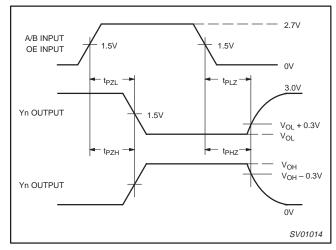
74LVT1403

## **AC WAVEFORMS (Continued)**

 $V_{M} = 1.5V$ ,  $V_{IN} = GND \text{ to } 2.7V$ 

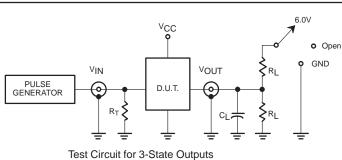


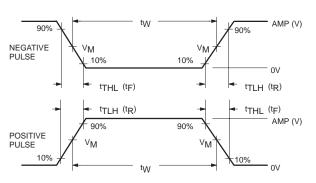
Waveform 3. 3-State Output Enable and Disable Times



Waveform 4. 3-State Output Enable and Disable Times

## **TEST CIRCUIT AND WAVEFORM**





 $V_M = 1.5V$ Input Pulse Definition

### **SWITCH POSITION**

TEST	SWITCH
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	6V
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

## **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $\begin{array}{ll} C_L = & Load \ capacitance \ includes \ jig \ and \ probe \ capacitance; \\ & see \ AC \ CHARACTERISTICS \ for \ value. \end{array}$ 

 $R_T$  = Termination resistance should be equal to  $Z_{OUT}$  of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS							
FAMILY	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>			
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns			

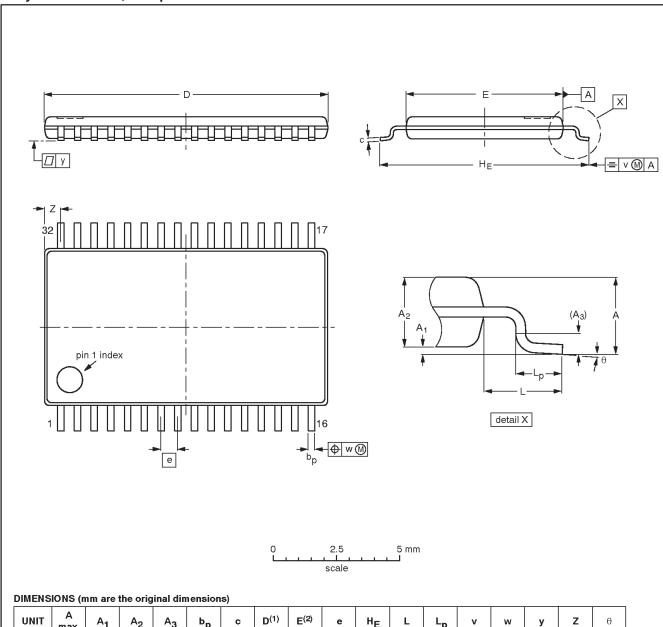
SV00092

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

TSSOP32: plastic thin shrink small outline package; 32 leads; body width 6.1 mm; lead pitch 0.65 mm

SOT487-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	ь <sub>р</sub>	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	٧	w	у	Z	θ
mm	1.10	0.15 0.05	0.95 0.85	0.25	0.30 0.19	0.20 0.09	11.10 10.90	6.20 6.00	0.65	8.30 7.90	1.00	0.75 0.50	0.20	0.10	0.10	0.78 0.48	8° 0°

## Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT487-1		MO-153			97-06-11

3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

**NOTES** 

## 3.3V combined 8-bit bus receiver and 4-bit bus driver

74LVT1403

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

#### **Definitions**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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